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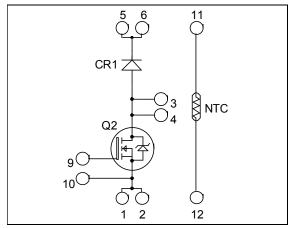


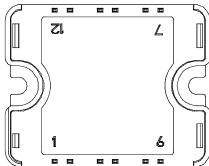




Boost chopper Super Junction MOSFET Power Module

$$\begin{split} V_{DSS} &= 600 V \\ R_{DSon} &= 24 m \Omega \ max \ @\ Tj = 25^{\circ} C \\ I_D &= 95 A \ @\ Tc = 25^{\circ} C \end{split}$$





Pins 1/2; 3/4; 5/6 must be shorted together

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- COOLMOS
 - Ultra low R_{DSon}
 - Low Miller capacitance
 - Ultra low gate charge
 - Avalanche energy rated
 - Very rugged
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

INSUIGE	e maximum radings				
Symbol	Parameter	Max ratings	Unit		
$V_{ m DSS}$	Drain - Source Breakdown Voltage		600	V	
I_D	Confinitoric Drain Current	$T_c = 25^{\circ}C$	95		
		$T_c = 80^{\circ}C$	70	Α	
I_{DM}	Pulsed Drain current	260	7		
V_{GS}	Gate - Source Voltage		±20	V	
R _{DSon}	Drain - Source ON Resistance		24	mΩ	
P_{D}	Maximum Power Dissipation	$T_c = 25$ °C	462	W	
I_{AR}	Avalanche current (repetitive and non repetitive)		15	A	
E_{AR}	Repetitive Avalanche Energy		3	ını I	
Eas	Single Pulse Avalanche Energy		1900	mJ	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$ $T_j = 25^{\circ}C$			350	μА
		$V_{GS} = 0V, V_{DS} = 600V$ $T_j = 125^{\circ}C$			600	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 47.5A$			24	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	2.1	3	3.9	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			200	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V ; V_{DS} = 25V$		14.4		nF
C_{oss}	Output Capacitance	f = 1MHz		17		ш
Q_{g}	Total gate Charge	$V_{GS} = 10V$		300		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 300 \text{V}$		68		nC
Q_{gd}	Gate – Drain Charge	$I_D = 95A$		102		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		21		ns
$T_{\rm r}$	Rise Time	$V_{GS} = 10V$		30		
$T_{d(off)}$	Turn-off Delay Time	$\begin{aligned} V_{Bus} &= 400V \\ I_D &= 95A \\ R_G &= 2.5\Omega \end{aligned}$		100		
T_{f}	Fall Time			45		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1350		T
E _{off}	Turn-off Switching Energy	$V_{GS} = 10V ; V_{Bus} = 400V$ $I_D = 95A ; R_G = 2.5\Omega$		1040		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2200		т
E _{off}	Turn-off Switching Energy	$V_{GS} = 10V ; V_{Bus} = 400V$ $I_D = 95A ; R_G = 2.5\Omega$	·	1270		μJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_i = 25$ °C $T_i = 125$ °C			100 500	μА
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		100		A
		$I_F = 100A$			1.6	2	
$V_{\rm F}$	Diode Forward Voltage	$I_F = 200A$			2		V
		$I_{\rm F} = 100 A$	$T_{i} = 125^{\circ}C$		1.3		
t_{rr}	Reverse Recovery Time	$I_F = 100A$ $V_R = 400V$	$T_j = 25$ °C		160		nc
			$T_j = 125$ °C		220		ns
Qrr	Reverse Recovery Charge	$di/dt = 200 A/\mu s \qquad T_j = 2$	$T_j = 25^{\circ}C$		290		nC
			$T_{i} = 125^{\circ}C$		1530		IIC



Thermal and package characteristics

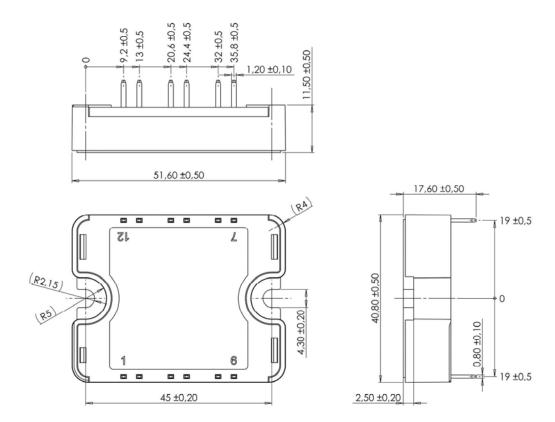
Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	Transis	tor			0.27	°C/W
	Junction to Case Thermal Resistance					0.55	7 C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
T_{C}	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight				80	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

	Symbol	Characteristic	Min	Тур	Max	Unit	
-	R ₂₅	Resistance @ 25°C		50		kΩ	l
	${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K	

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature } \\ R_T: \text{Thermistor value at T}$$

SP1 Package outline (dimensions in mm)

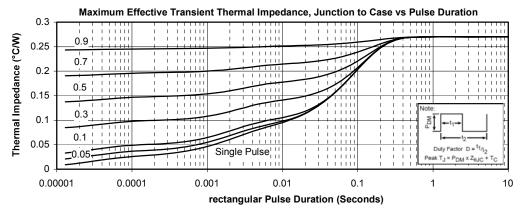


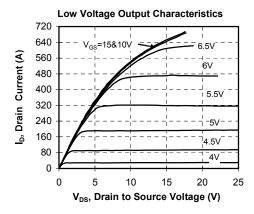
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

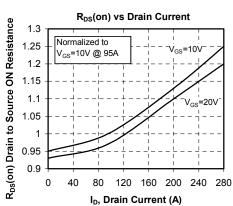
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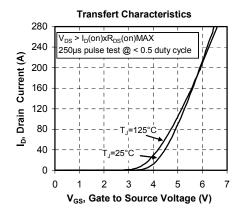


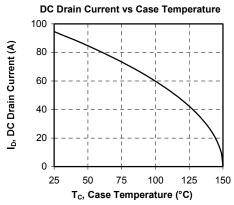
Typical Performance Curve



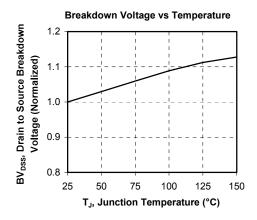


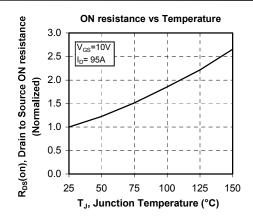


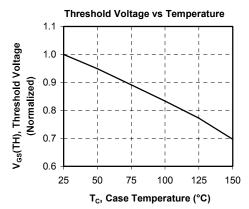


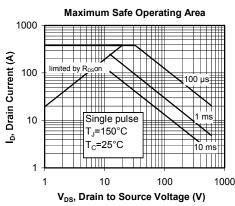


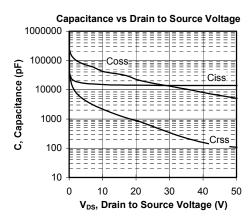


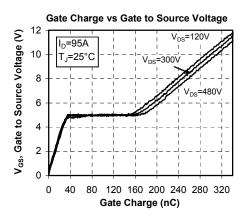




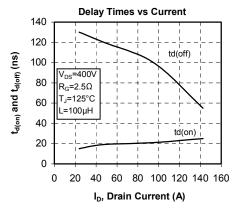


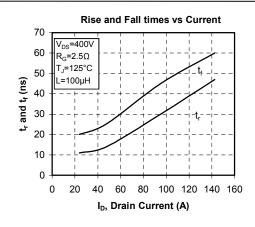


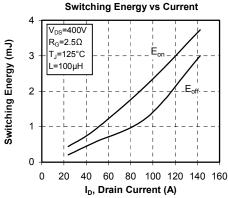


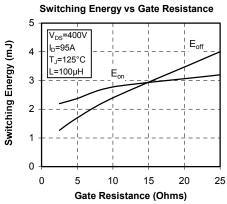


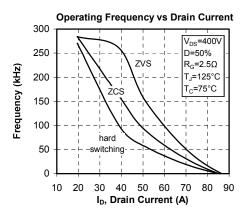


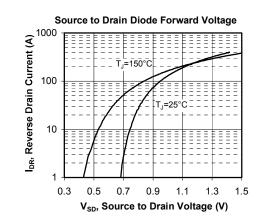












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